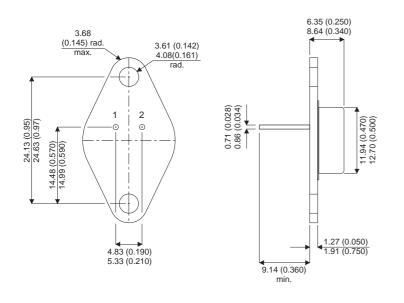


# 2N3741R

#### MECHANICAL DATA

Dimensions in mm



## POWER TRANSISTORS PNP SILICON

#### **FEATURES**

- Hermetically Package.
- Low Saturation Voltage
- High Gain

TO66 Package (TO-213AA)

Complementary to NPN 2N3740

Pin 1 = Base Pin 2 = Emitter Case = Collector

### ABSOLUTE MAXIMUM RATINGS (T<sub>case</sub> = 25°C unless otherwise stated)

V <sub>CBO</sub>	Collector – Base Voltage	80V		
V <sub>CEO</sub>	Collector – Emitter Voltage ( $I_B = 0$ )	80V		
V <sub>EBO</sub>	Emitter – Base Voltage (I <sub>C</sub> = 0)	7V		
I <sub>C</sub>	Collector Current	4A		
I <sub>C(PK)</sub>	Peak Collector Current	10A		
I <sub>B</sub>	Base Current	2A		
PD	Total Device Dissipation at $T_{case} = 25^{\circ}C$	25W		
	Derate 25°C	0.143W/°C		
T <sub>stg</sub>	Operating and Storage Temperature Range	–65 to 200°C		

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.





# ELECTRICAL CHARACTERISTICS (T<sub>case</sub> = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit			
	ELECTRICAL CHARACTERISTICS									
V <sub>CEO(sus)*</sub>	Collector – Emitter Sustaining Voltage	I <sub>C</sub> = 100mA	I <sub>B</sub> = 0	80			V			
I <sub>CBO</sub>	Collector Base Cut–Off Current	V <sub>CB</sub> = 80V	$I_E = 0$			100	μΑ			
I <sub>CEO</sub>	Collector Emiiter Cut–Off Current	$V_{CE} = 60V$	I <sub>B</sub> = 0			1.0	mA			
I <sub>CEX</sub>	Collector Cut–Off Current	$V_{CE} = 80V$	$V_{BE(OFF)} = 1.5V$			100	μA			
		V <sub>CE</sub> = 60V	$V_{BE(OFF)} = 1.5V$		1	mA				
			$T_{\rm C} = 150^{\circ}{\rm C}$							
I <sub>EBO</sub>	Emitter Base Cut–Off Current	$V_{EB} = 7V$				0.5	mA			
h <sub>FE*</sub>	DC Current Gain	I <sub>C</sub> = 100mA	$V_{CE} = 1V$	40			- -			
		I <sub>C</sub> = 250mA	$V_{CE} = 1V$	30		180				
		I <sub>C</sub> = 500mA	$V_{CE} = 1V$	20						
		I <sub>C</sub> = 1A	$V_{CE} = 1V$	10						
V <sub>CE(sat)*</sub>	Collector – Emitter Saturation Voltage	I <sub>C</sub> = 1A	I <sub>B</sub> = 125mA			0.6	V			
V <sub>BE*</sub>	Base – Emitter Saturation Voltage	I <sub>C</sub> = 250mA	I <sub>B</sub> = 1V			1.0				
	DYNAMIC CHARACTERISTICS			·	·					
f <sub>t</sub>	Transition Frequency	I <sub>C</sub> = 100mA	$V_{CE} = 10V$	3			MHz			
			f = 1MHz	4						
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V	$I_{\rm C} = 0$			100	ηE			
			f = 100KHz				pF			
h <sub>fe</sub>	Small Signal Current Gain	I <sub>C</sub> = 50mA	V <sub>CE</sub> = 10V 25							
			f = 1KHz	20						

\* Pulse Width  $\leq 300 \mu s$  , Duty Cycle < 2%

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